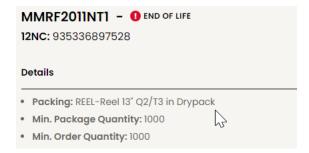
MMRF2011N

Features - RF LDMOS Wideband Integrated Power Amplifier, 698-960 MHz, 1.6 W Avg., 28 V

Package - HQFN24, plastic, thermal enhanced quad flatpack; no leads; 24 terminals; 0.8 mm pitch; 8 mm x 8 mm x 2.1 mm body



Operating Features

No information available

Environmental

Part/12NC	PbFree	EU RoHS	Halogen Free	RHF Indicator	2nd Level Interconnect	REACH SVHC	Weight (mg)
MMRF2011NT1(935336897528)	No	Yes Certificate Of Analysis (CoA)	Yes	H	e3	REACH SVHC	399.6

Quality

Part/12NC	Safe Assure Functional Safety	Moisture Sensitivity Level (MSL)	Peak Package Body Temperature (PPT)		Maximum Time at Peak Temperatures (s)	
		Lead Soldering	Lead Soldering	15ad Free Soldering	Lead Soldering	Lead Free Soldering
MMRF2011NT1 (935336897528)	No	3	260	260	40	40

Shipping

Part/12NC	Harmonized Tariff (US) <u>Disclaimer</u>	Export Control Classification Number (US)	
MMRF2011NT1 (935336897528)	854233	EAR99	

Discontinued and Replacement Part Data

Part/12NC	Discontinuance Notice	Last Time Buy Date	Last Time Delivery Date	Replacement
MMRF2011NT1 (935336897528)	NOTICE	2021-12-01	2022-05-31	MW7IC915NT1 (935317147528)

Product Change Notice

Part/12NC	Issue Date	Effective Date	PCN	Title
MMRF2011NT1 (935336897528)	2020-12-15	2020-12-16	2020110111	NXP Will Add a Sealed Date to the Product Label
MMRF2011NT1 (935336897528)	2020-09-24	2020-09-25	202009028DN	NXP Semiconductors Oak Hill Fab Scale Down: Product Discontinuation Notification